

RJK0628JPE

60 V - 160 A - N Channel MOS FET
High Speed Power Switching

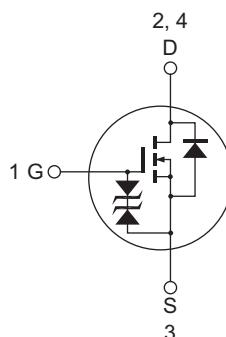
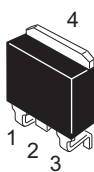
R07DS0336EJ0200
Rev.2.00
Aug 29, 2012

Features

- For Automotive application
- AEC-Q101 compliant
- Low on-resistance : $R_{DS(on)} = 2.6 \text{ m}\Omega$ typ.
- Capable of 4.5 V gate drive
- Low input capacitance : $C_{iss} = 5400 \text{ pF}$ typ

Outline

RENESAS Package code: PRSS0004AE-B
(Package name: LDPAK(S)-(1))



1. Gate
2. Drain
3. Source
4. Drain

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	60	V
Gate to source voltage	V_{GSS}	+20 / -5	V
Drain current	I_D	160	A
Drain peak current	I_D (pulse) ^{Note1}	640	A
Body-drain diode reverse drain current	I_{DR} ^{Note3}	160	A
Body-drain diode reverse drain peak current	I_{DR} (pulse) ^{Note1}	640	A
Avalanche current	I_{AP} ^{Note2}	65	A
Avalanche energy	E_{AR} ^{Note2}	362	mJ
Channel dissipation	P_{ch} ^{Note3}	192	W
Channel temperature	T_{ch} ^{Note4}	175	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. $T_{ch} = 25^\circ\text{C}$, $R_g \geq 50 \Omega$

3. $T_c = 25^\circ\text{C}$

4. AEC-Q101 compliant

Thermal Impedance Characteristics

- Channel to case thermal impedance θ_{ch-c} : 0.781°C/W

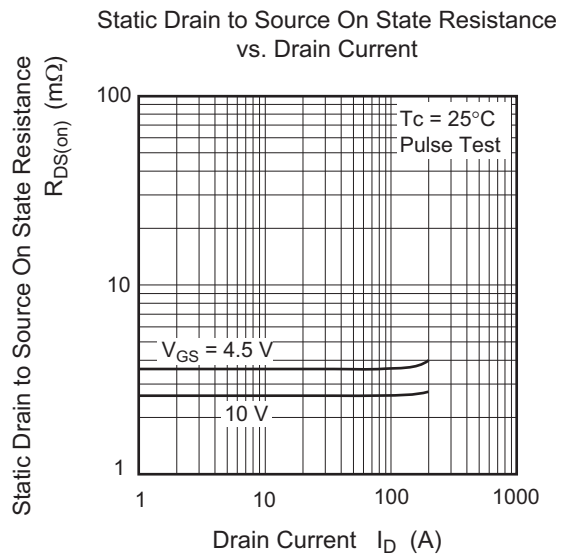
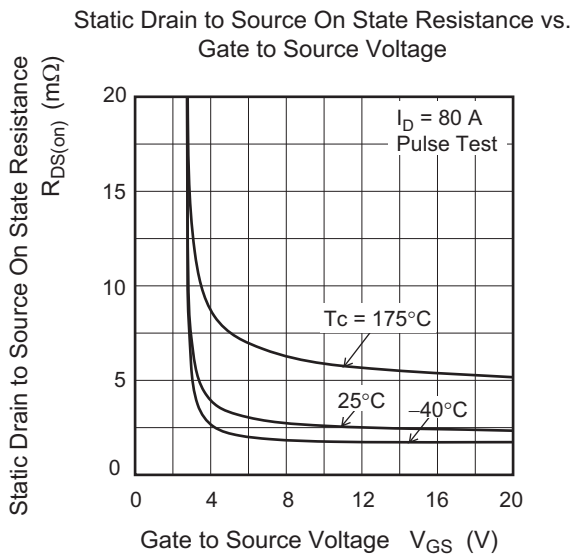
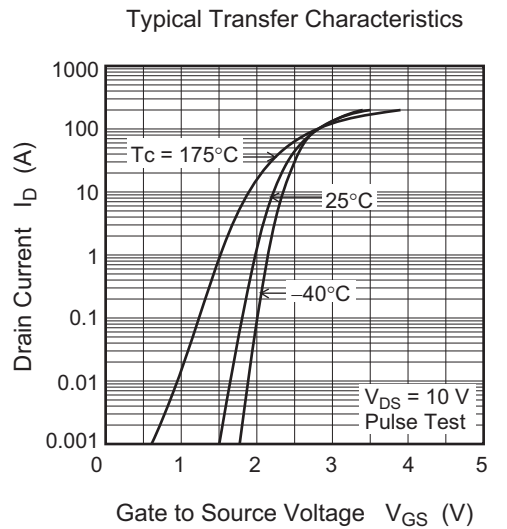
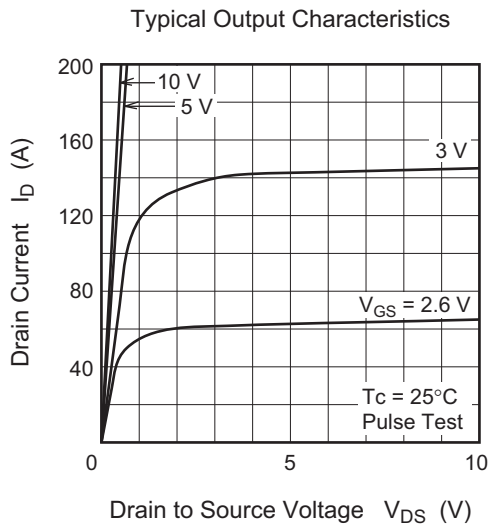
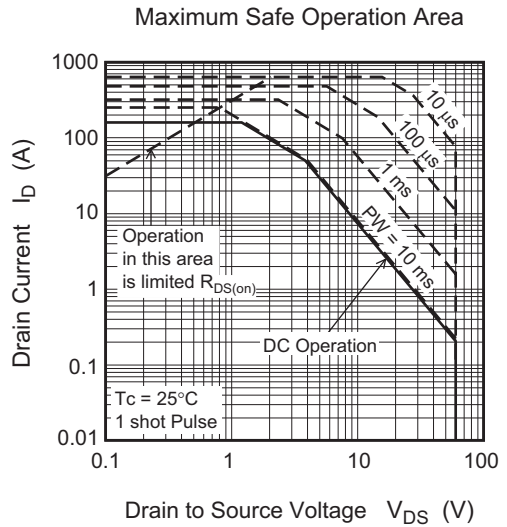
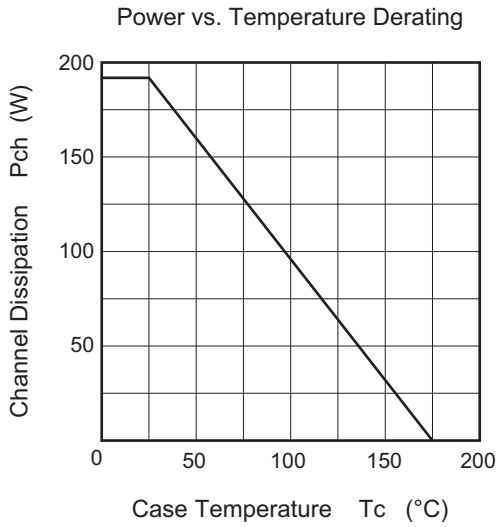
Electrical Characteristics

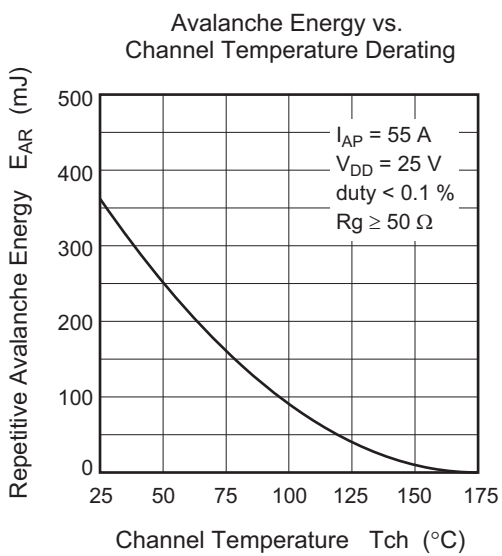
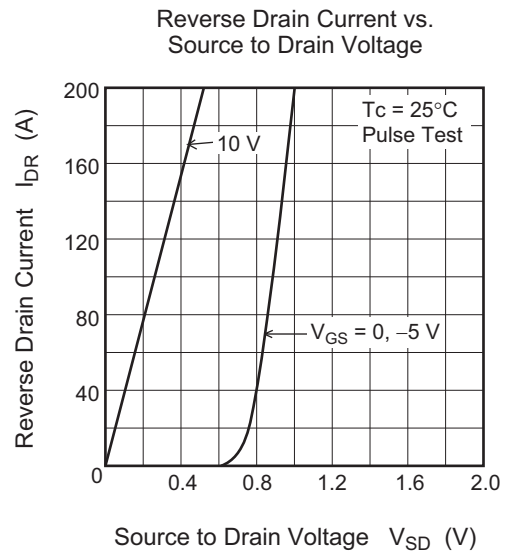
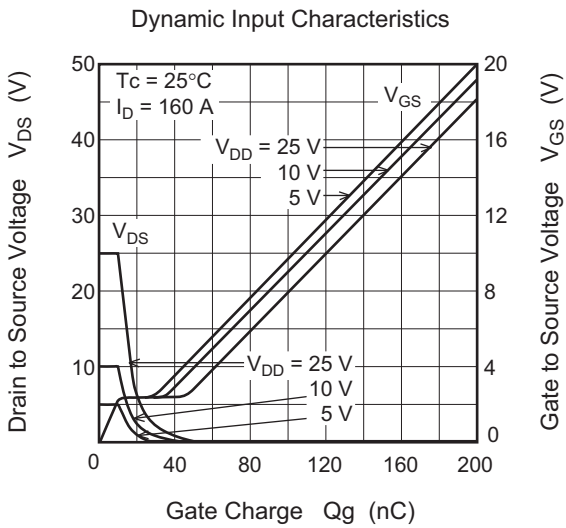
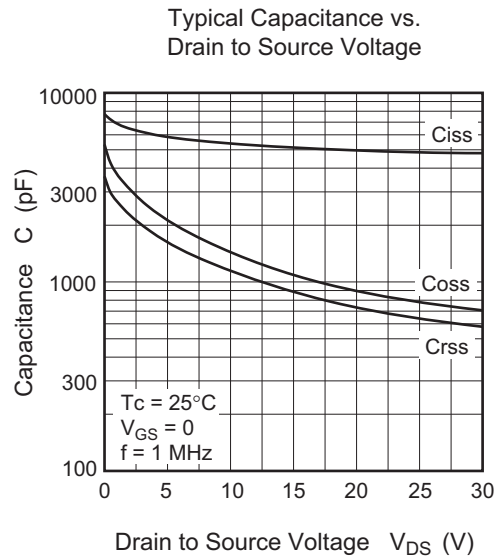
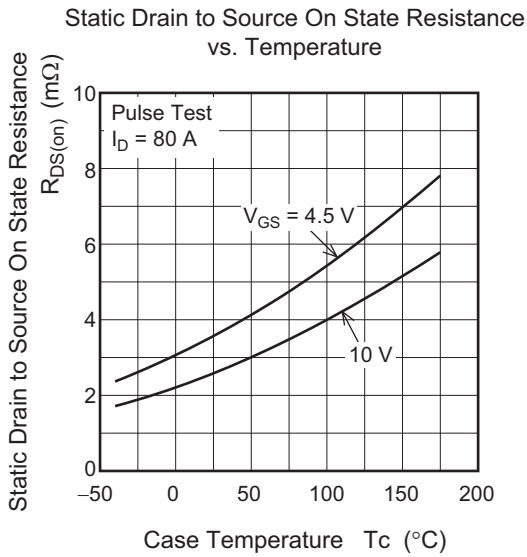
(Ta = 25°C)

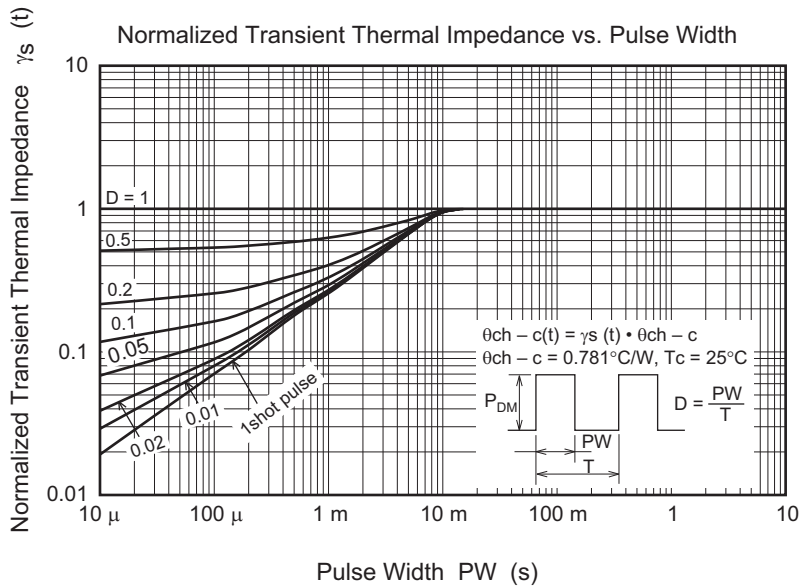
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Gate to source leak current	I_{GSS}	—	—	±10	μA	$V_{GS} = +20/-5 V, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	10	μA	$V_{DS} = 60 V, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$I_D = 1 mA, V_{DS} = 10 V$
Static drain to source on state resistance	$R_{DS(on)}$	—	2.6	3.2	mΩ	$I_D = 80 A, V_{GS} = 10 V$ ^{Note5}
	$R_{DS(on)}$	—	3.6	4.9	mΩ	$I_D = 80 A, V_{GS} = 4.5 V$ ^{Note5}
Input capacitance	C_{iss}	—	5400	—	pF	$V_{DS} = 10 V,$ $V_{GS} = 0$ $f = 1 MHz$
Output capacitance	C_{oss}	—	1400	—	pF	
Reverse transfer capacitance	C_{rss}	—	1100	—	pF	
Total gate charge	Q_g	—	120	—	nC	$V_{DD} = 25 V, V_{GS} = 10 V,$ $I_D = 80 A$
Gate to source charge	Q_{gs}	—	15	—	nC	
Gate to drain charge	Q_{gd}	—	35	—	nC	
Turn-on delay time	$t_{d(on)}$	—	20	—	ns	$I_D = 80 A, R_L = 0.375 \Omega$ $V_{GS} = 10 V, R_G = 4.7 \Omega$
Rise time	t_r	—	45	—	ns	
Turn-off delay time	$t_{d(off)}$	—	120	—	ns	
Fall time	t_f	—	60	—	ns	
Body-drain diode forward voltage	V_{DF}	—	0.96	1.25	V	$I_F = 160 A, V_{GS} = 0$ ^{Note5}
Body-drain diode reverse recovery time	t_{rr}	—	60	—	ns	$I_F = 80 A, V_{GS} = 0,$ $di_F/dt = 100 A/\mu s$

Note: 5. Pulse test

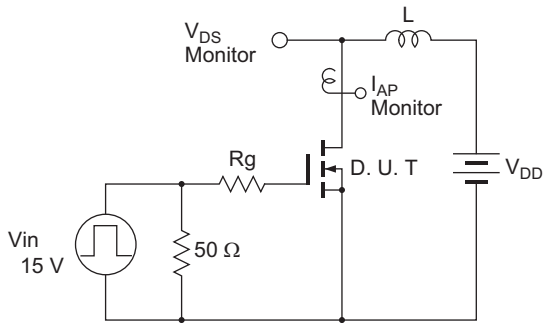
Main Characteristics





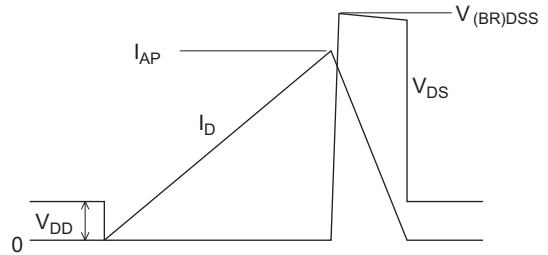


Avalanche Test Circuit

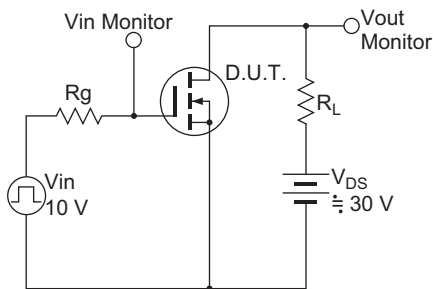


Avalanche Waveform

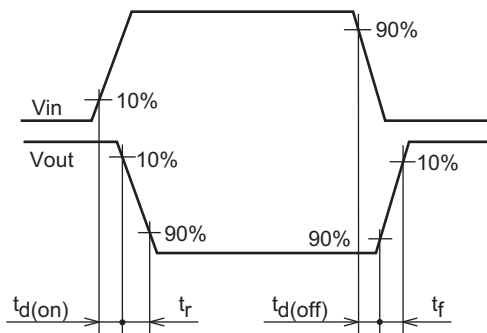
$$E_{AR} = \frac{1}{2} L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$



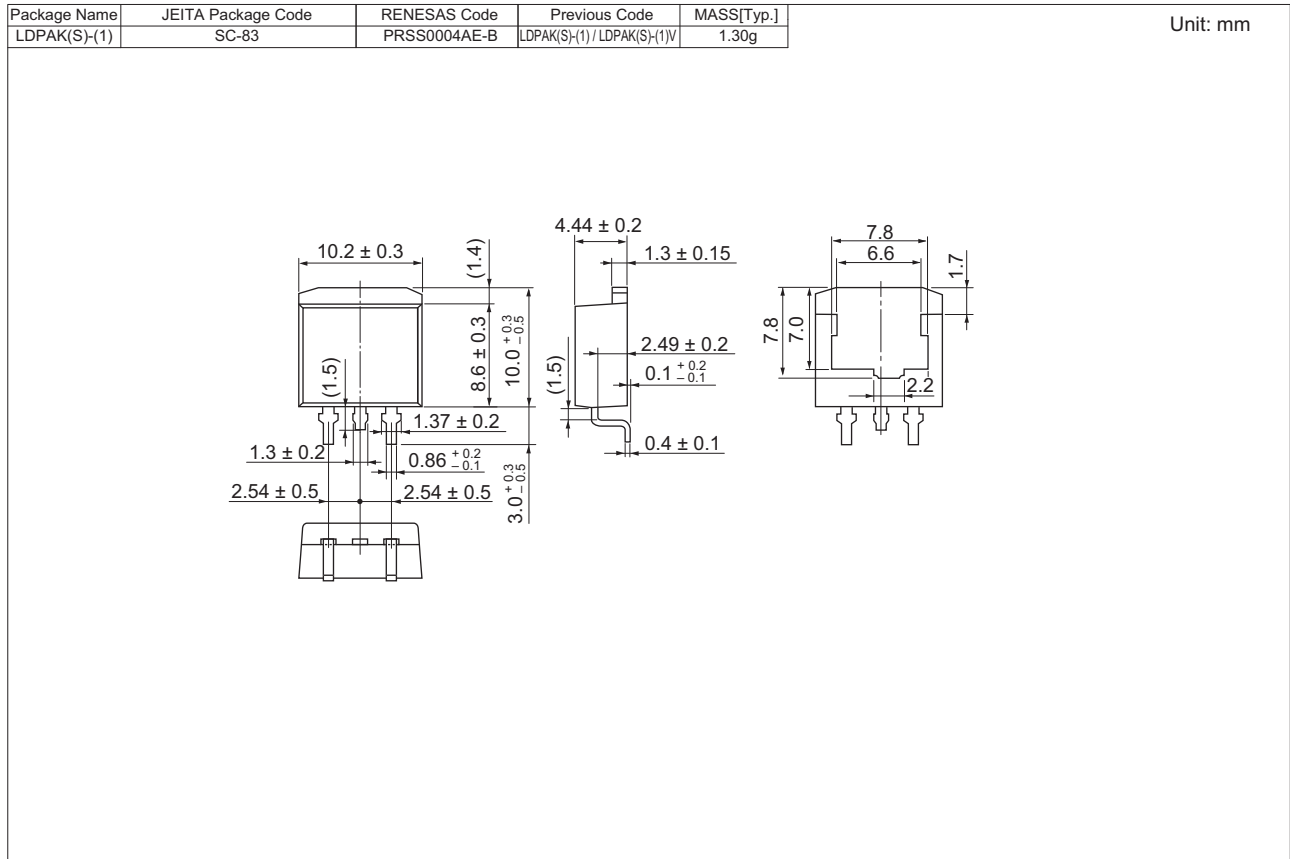
Switching Time Test Circuit



Switching Time Waveform



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0628JPE-00-J3	1000 pcs	Taping (Sinistrorse)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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